



Rev. V1

(continued)

The RF Line NPN Silicon Power Transistor 25W(PEP), 30MHz, 28V

Designed for high gain driver and output linear amplifier stages in 1.5 to 30 MHz HF/SSB equipment.

- Specified 28 V, 30 MHz characteristics Output power = 25 W (PEP) Minimum gain = 22 dB Efficiency = 35%
- Intermodulation distortion @ 25 W (PEP) —IMD = -30 dB (max)
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Class A and AB characterization
- BLX 13 equivalent

Product Image



MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	V _{CEO}	35	Vdc	
Collector–Base Voltage	V _{CBO}	65	Vdc	
Emitter–Base Voltage	V _{EBO}	4.0	Vdc	
Collector Current — Continuous	Ιc	3.0	Adc	
Withstand Current — 5 s	-	6.0	Adc	
Total Device Dissipation @ T _C = 25°C (1) Derate above 25°C	PD	70 0.4	Watts W/°C	
Storage Temperature Range	T _{stg}	-65 to +150	°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Case	R _{eJC}	2.5	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I _C = 50 mAdc, I _B = 0)	V _{(BR)CEO}	35	_	—	Vdc
Collector-Base Breakdown Voltage (I _C = 50 mAdc, I _E = 0)	V _{(BR)CBO}	65	_	—	Vdc
Emitter–Base Breakdown Voltage (I _E = 10 mAdc, I _C = 0)	V _{(BR)EBO}	4.0	_	_	Vdc
Collector Cutoff Current (V _{CE} = 28 Vdc, V _{BE} = 0)	ICES	_	_	10	mAdc

NOTE:

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

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ELECTRICAL CHARACTERISTICS — continued (T _C = 25°C) Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS		ļ		ļ	
DC Current Gain (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc)	h _{FE}	10	35	-	_
DYNAMIC CHARACTERISTICS		•	1		
Output Capacitance (V _{CB} = 30 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	-	60	80	pF
FUNCTIONAL TESTS (SSB)		1	1	1	
Common–Emitter Amplifier Gain (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA)	G _{PE}	22	25	-	dB
Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA)	η	35	-	-	%
Intermodulation Distortion (2) (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA)	IMD _(d3)	-	-35	-30	dB
Load Mismatch (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA, VSWR 30:1 at All Phase Angles)	Ψ	No Degradation in Output Power			
CLASS A PERFORMANCE					
Intermodulation Distortion (2) and Power Gain	G _{PE}	_	23.5 -40	_	dB

Intermodulation Distortion (2) and Power Gain	GPE	_	23.5	_	dB
(V _{CC} = 28 Vdc, P _{out} = 8.0 W (PEP), f1 = 30 MHz,	IMD _(d3)	—	-40	—	
f2 = 30.001 MHz, I _{CQ} = 1.2 Adc)	IMD _(d5)	—	-55	—	

NOTE:

2. To Mil-Std-1311 Version A, Test Method 2204B, Two Tone, Reference each Tone.



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Adjust Bias (Base) for I_{CQ} = 20 mA with No RF Applied

Figure 1. 30 MHz Linear Test Circuit



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Figure 5. Intermodulation Distortion versus Output Power



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Figure 6. DC Safe Operating Area



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Figure 9. Series Equivalent Input Impedance





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Unless otherwise noted, tolerances are inches $\pm .005$ " [millimeters ± 0.13 mm]



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